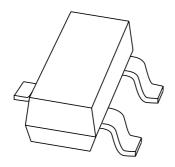
DISCRETE SEMICONDUCTORS

DATA SHEET



BAV74High-speed double diode

Product specification Supersedes data of 1999 May 11 2004 Jan 14





High-speed double diode

BAV74

FEATURES

- Small plastic SMD package
- High switching speed: max. 4 ns
- Continuous reverse voltage: max. 50 V
- Repetitive peak reverse voltage: max. 60 V
- Repetitive peak forward current: max. 450 mA.

• High-speed switching in thick and thin-film circuits.

DESCRIPTION

The BAV74 consists of two high-speed switching diodes with common cathodes, fabricated in planar technology, and encapsulated in a small SOT23 plastic SMD package.

MARKING

Note

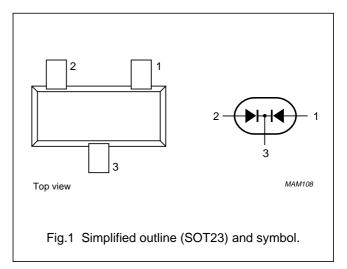
TYPE NUMBER	MARKING CODE(1)	
BAV74	JA*	

APPLICATIONS

TYPE NUMBER	MARKING CODE(1)
BAV74	JA*

PINNING

PIN	DESCRIPTION		
1	anode (a1)		
2	anode (a2)		
3	cathode		



LIMITING VALUES

* = p : Made in Hong Kong. * = t : Made in Malaysia. * = W: Made in China.

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Per diode					
V_{RRM}	repetitive peak reverse voltage		_	60	٧
V_R	continuous reverse voltage		_	50	V
I _F	continuous forward current	single diode loaded; note 1; see Fig.2	_	215	mA
		double diode loaded; note 1; see Fig.2	_	125	mA
I _{FRM}	repetitive peak forward current		_	450	mA
I _{FSM}	non-repetitive peak forward	square wave; T _j = 25 °C prior to surge; see Fig.4			
	current	t = 1 μs	_	4	Α
		t = 1 ms	_	1	Α
		t = 1 s	_	0.5	Α
P _{tot}	total power dissipation	T _{amb} = 25 °C; note 1	_	250	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		_	150	°C

Note

1. Device mounted on an FR4 printed-circuit board.

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ORDERING INFORMATION

TYPE NUMBER	PACKAGE			
TTPE NOWIDER	NAME DESCRIPTION VERSION			
BAV74	 plastic surface mounted package; 3 leads 		SOT23	

ELECTRICAL CHARACTERISTICS

 $T_i = 25$ °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MAX.	UNIT
Per diode				·
V _F	forward voltage	see Fig.3		
		I _F = 1 mA	715	mV
		I _F = 10 mA	855	mV
		I _F = 100 mA	1.0	V
I _R	reverse current	see Fig.5		
		V _R = 25 V	30	nA
		V _R = 50 V	0.1	μΑ
		V _R = 25 V; T _j = 150 °C	30	μΑ
		$V_R = 50 \text{ V}; T_j = 150 ^{\circ}\text{C}$	100	μΑ
C _d	diode capacitance	f = 1 MHz; V _R = 0; see Fig.6	1.5	pF
t _{rr}	reverse recovery time	when switched from I_F = 10 mA to I_R = 10 mA; R_L = 100 Ω ; measured at I_R = 1 mA; see Fig.7	4	ns
V _{fr}	forward recovery voltage	when switched from $I_F = 10$ mA; $t_r = 20$ ns; see Fig.8	1.75	V

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th(j-tp)}	thermal resistance from junction to tie-point		360	K/W
R _{th(j-a)}	thermal resistance from junction to ambient	note 1	500	K/W

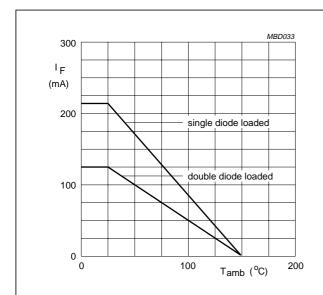
Note

1. Device mounted on an FR4 printed-circuit board.

High-speed double diode

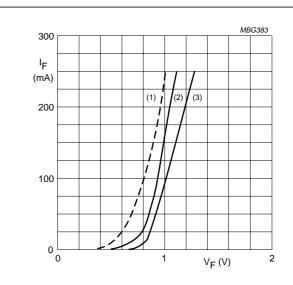
BAV74

GRAPHICAL DATA



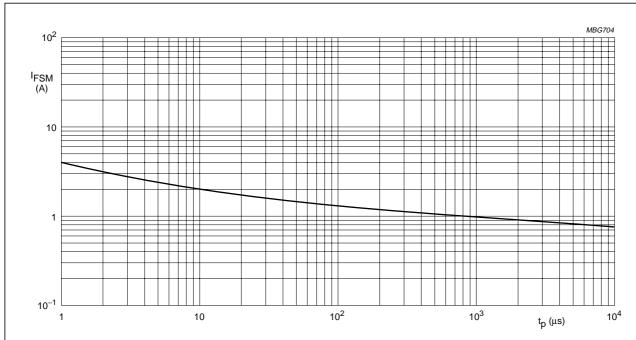
Device mounted on an FR4 printed-circuit board.

Fig.2 Maximum permissible continuous forward current as a function of ambient temperature.



- (1) $T_i = 150$ °C; typical values.
- (2) $T_j = 25$ °C; typical values.
- (3) $T_j = 25$ °C; maximum values.

Fig.3 Forward current as a function of forward voltage.



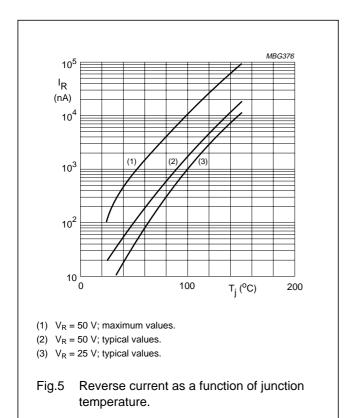
Based on square wave currents.

 $T_j = 25$ °C prior to surge.

Fig.4 Maximum permissible non-repetitive peak forward current as a function of pulse duration.

High-speed double diode

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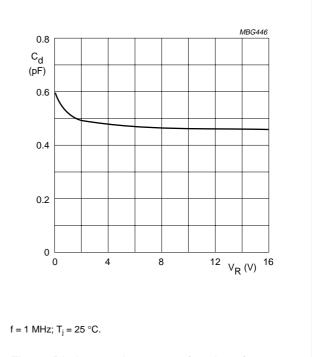
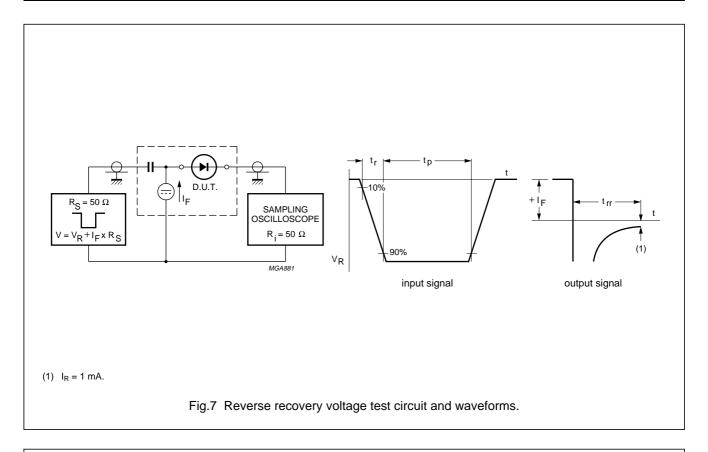
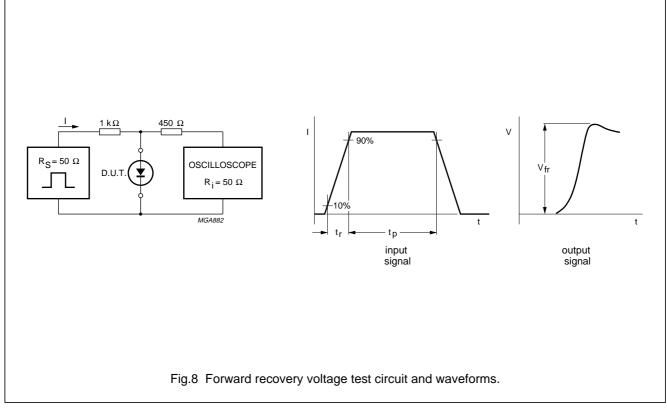


Fig.6 Diode capacitance as a function of reverse voltage; typical values.

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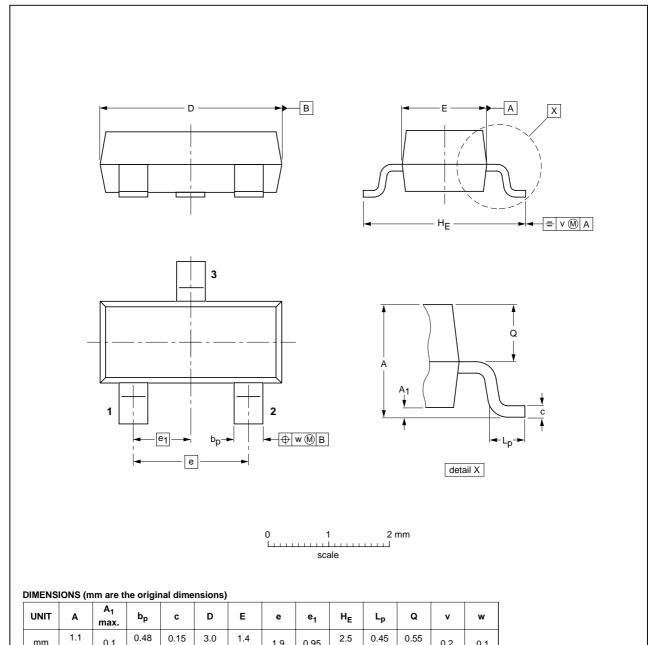
High-speed double diode

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PACKAGE OUTLINE

Plastic surface mounted package; 3 leads

SOT23



OUTLINE	REFERENCES			EUROPEAN	ISSUE DATE	
VERSION	ON IEC JEDEC EIAJ		PROJECTION	ISSUE DATE		
SOT23		TO-236AB				97-02-28 99-09-13

0.2

0.1

0.95

1.9

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0.9

High-speed double diode

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DATA SHEET STATUS

LEVEL	DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS(2)(3)	DEFINITION
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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III	Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Relevant changes will be communicated via a Customer Product/Process Change Notification (CPCN).

Notes

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- 2. The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.
- 3. For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

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Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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